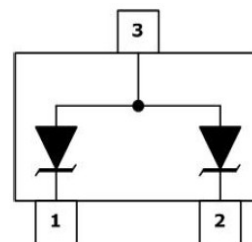


DESCRIPTION

The dual monolithic silicon Zener diodes are designed for applications requiring transient overvoltage protection capability. They are intended for use in voltage and ESD sensitive equipment such as computers, printers, business machines, communication systems, medical equipment and other applications. Their dual junction common anode design protects two separate lines using only one package. These devices ideal for situations where board space is at a premium.



FEATURES

- SOT-23 package allows either two separate unidirectional configurations or a single bidirectional configuration.
- Working peak reverse voltage 3V to 22V
- Standard Zener breakdown voltage 5.6V to 27V
- Peak power 24 or Watts @ 1.0ms (unidirectional) per Figure 6 Waveform
- ESD Rating:
Class 3B (>16kV) per the Human Body Model
Class C (>400V) per Machine Model
- ESD Rating of IEC61000-4-2 level 4, ± 30kV contact Discharge
- Low leakage < 5.0µA

MACHANICAL DATA

- SOT-23 package
- Flammability Rating: UL 94V-0
- Packaging: Tape and Reel
- High temperature soldering guaranteed:260°C/10s

APPLICATIONS

- Computers
- Printers
- Business Machines
- Communication systems
- Medical equipment

ABSOLUTE MAXIMUM RATING

Symbol	Parameter	Value	Units
P _{PK}	Peak Power Dissipation @1.0ms		
	MMBZ5V6AL thru MMBZ6V8AL	24	W
	MMBZ12VAL thru MMBZ27VAL	40	
P _D	Total Power Dissipation	200	mW
T _{OPT}	Operating Temperature	-55/+150	°C
T _{STG}	Storage Temperature	-55/+150	°C

24 WATTS

ELECTRICAL CHARACTERISTICS (Tamb=25°C)

UNIDIRECTIONAL (Circuit tied to Pins 1 and 3 or Pins 2 to 3)

Part Number	Device Marking	V _{RWM}	I _R	V _{BR}			Z _{ZT}	Z _{ZK}		V _C		
		(V)	(μA)	(V)			(Ω)	(Ω)	(mA)	(V)	(A)	
			@ V _{RWM}	Min	Nom	Max	@ I _T	Max @ I _{ZT}	Max	@ I _{ZK}	Max	@ I _{PP}
MMBZ5V6AL	5A6	3.0	5.0	5.32	5.6	5.88	20	11	1600	0.25	8.0	3.0
MMBZ6V2AL	6A2	3.0	0.5	5.89	6.2	6.51	1.0	--	--	--	8.7	2.76
MMBZ6V8AL	6A8	4.5	0.5	6.46	6.8	7.14	1.0	--	--	--	9.6	2.5

V_F=0.9V Max @ I_F=10mA

40 WATTS

ELECTRICAL CHARACTERISTICS (Tamb=25°C)

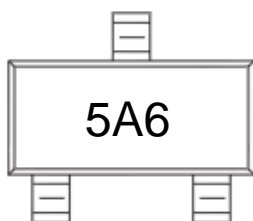
UNIDIRECTIONAL (Circuit tied to Pins 1 and 3 or Pins 2 to 3)

Part Number	Device Marking	V _{RWM}	I _R	V _{BR}				V _C (note1)	
		(V)	(nA)	(V)			(mA)	(V)	(A)
			@ V _{RWM}	Min	Nom	Max	@ I _T	Max	@ I _{PP}
MMBZ12VAL	12A	8.5	200	11.40	12	12.60	1	17	2.35
MMBZ15VAL	15A	12.0	50	14.25	15	15.75	1	21	1.90
MMBZ18VAL	18A	14.5	50	17.10	18	18.90	1	25	1.60
MMBZ27VAL	27A	22.0	50	25.65	27	28.35	1	40	1.0

V_F=0.9V Max @ I_F=10mA

Note 1: Surge Current waveform per Figure 5

Marking



ELECTRICAL CHARACTERISTICS CURVE

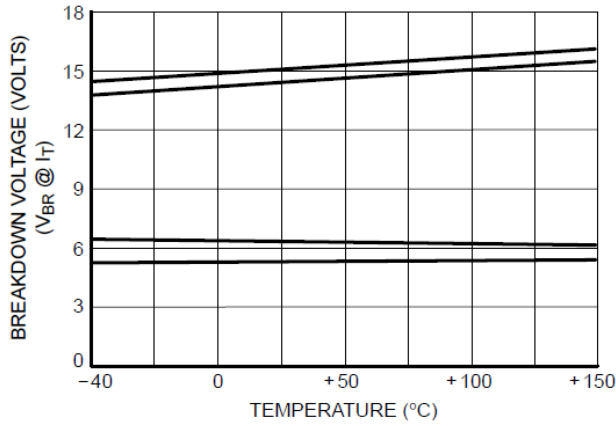


Figure 1. Typical Breakdown Voltage versus Temperature

(Upper curve for each voltage is bidirectional mode, lower curve is unidirectional mode)

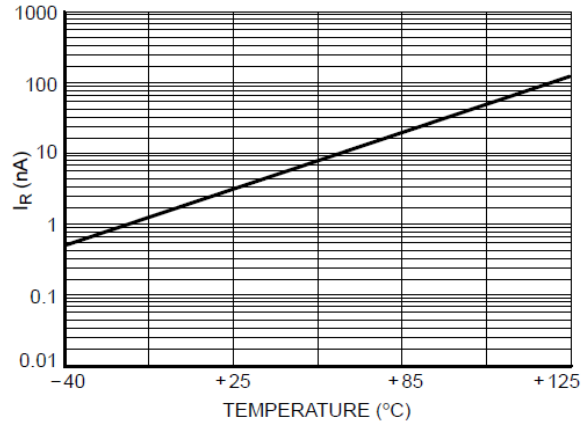


Figure 2. Typical Leakage Current versus Temperature

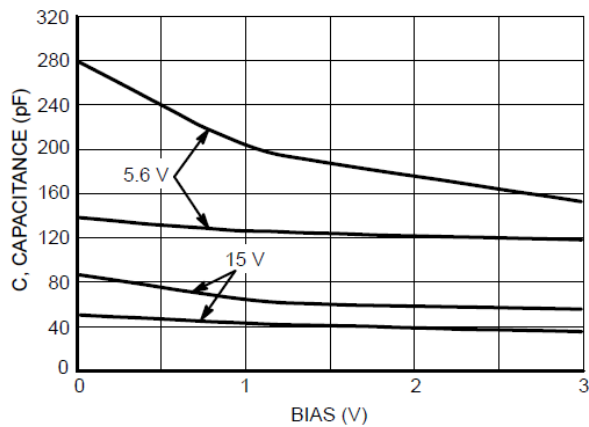


Figure 3. Typical Capacitance versus Bias Voltage

(Upper curve for each voltage is unidirectional mode, lower curve is bidirectional mode)

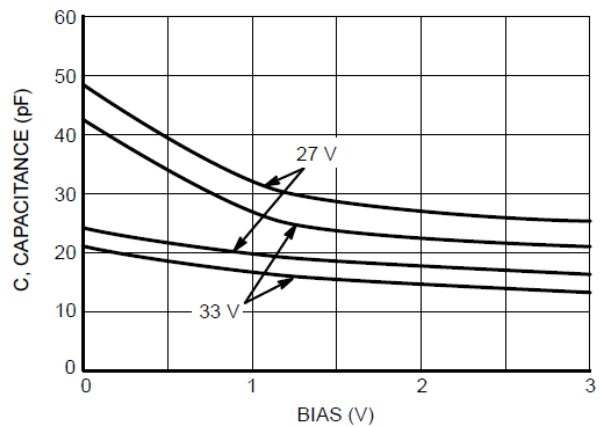


Figure 4. Typical Capacitance versus Bias Voltage

(Upper curve for each voltage is unidirectional mode, lower curve is bidirectional mode)

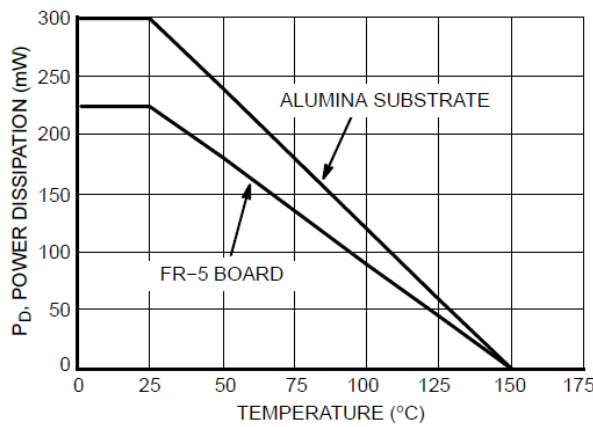


Figure 5. Steady State Power Derating Curve

ELECTRICAL CHARACTERISTICS CURVE

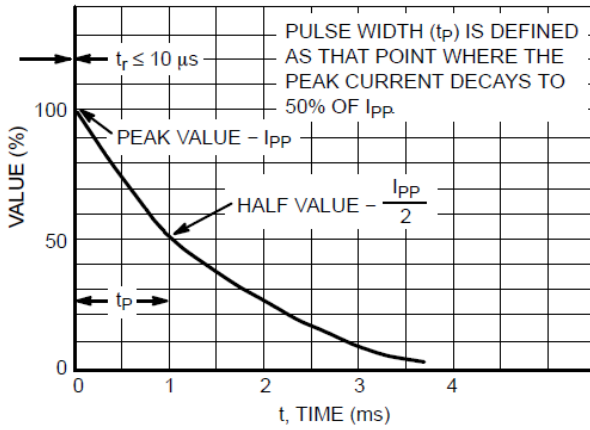


Figure 6. Pulse Waveform

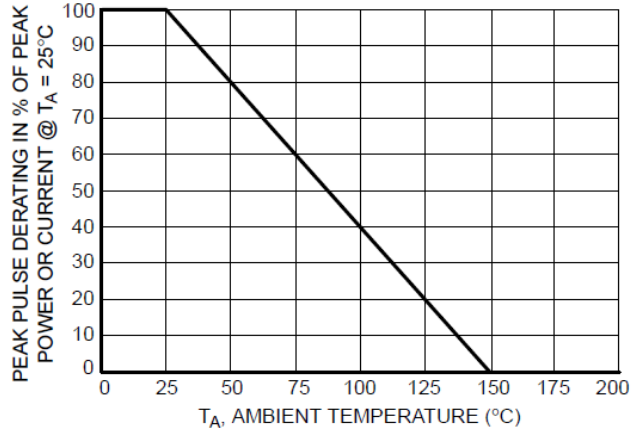


Figure 7. Pulse Derating Curve

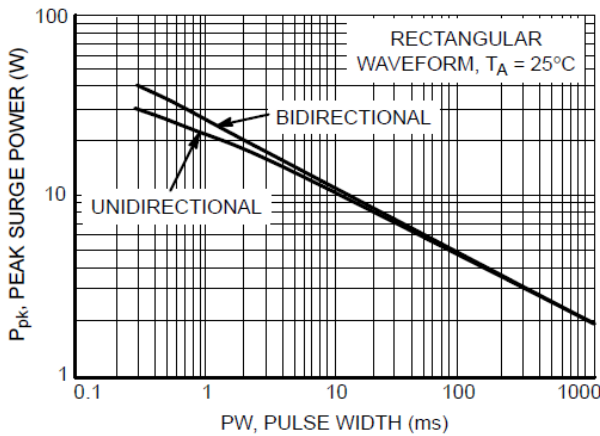


Figure 8. Maximum Non-repetitive Surge Power, P_{pk} versus PW

Power is defined as $V_{RSM} \times I_Z(pk)$ where V_{RSM} is the clamping voltage at $I_Z(pk)$.

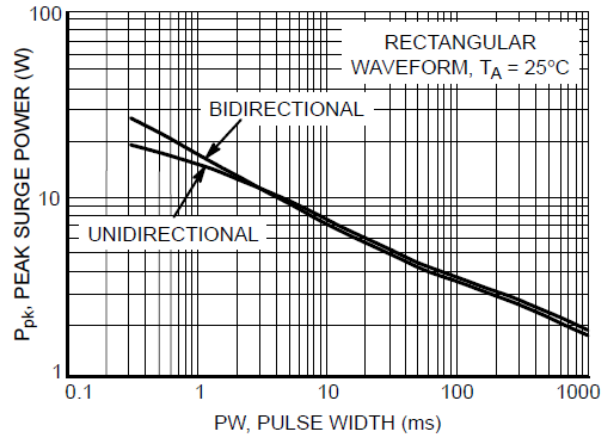
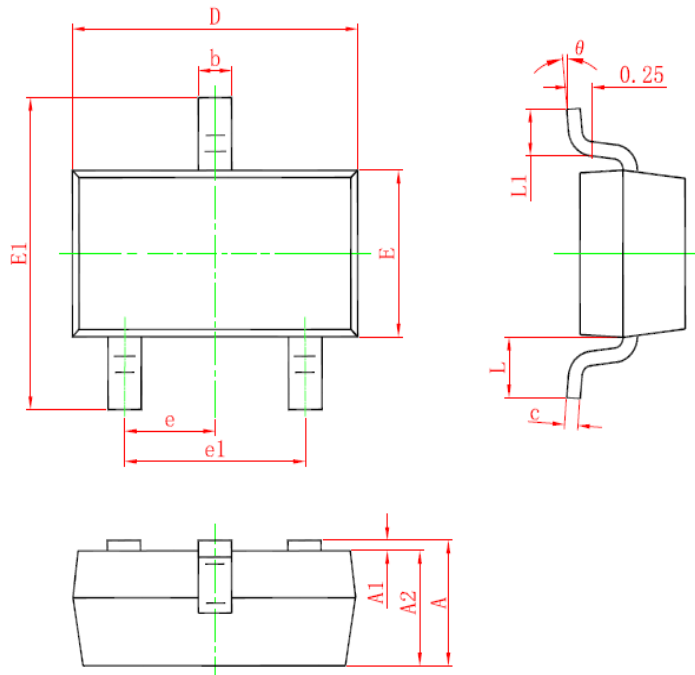


Figure 9. Maximum Non-repetitive Surge Power, $P_{pk}(NOM)$ versus PW

Power is defined as $V_Z(NOM) \times I_Z(pk)$ where $V_Z(NOM)$ is the nominal Zener voltage measured at the low test current used for voltage classification.

SOT 23 PACKAGE OUTLINE DIMENSIONS



Symbol	Dimensions In Millimeters		Dimensions In Inches	
	Min.	Max.	Min.	Max.
A	0.900	1.150	0.035	0.045
A1	0.000	0.100	0.000	0.004
A2	0.900	1.050	0.035	0.041
b	0.300	0.500	0.012	0.020
c	0.080	0.150	0.003	0.006
D	2.800	3.000	0.110	0.118
E	1.200	1.400	0.047	0.055
E1	2.250	2.550	0.089	0.100
e	0.950 TYP.		0.037 TYP.	
e1	1.800	2.000	0.071	0.079
L	0.550 REF.		0.022 REF.	
L1	0.300	0.500	0.012	0.020
θ	0°	8°	0°	8°

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